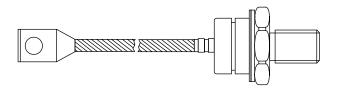


Vishay High Power Products

Standard Recovery Diodes (Stud Version), 200 A



DO-205AC (DO-30)

FEATURES

- Wide current range
- High voltage ratings up to 2400 V
- High surge current capabilities
- · Stud cathode and stud anode version
- Standard JEDEC types
- Compression bonded encapsulations
- · RoHS complaint
- Lead (Pb)-free
- Designed and qualified for industrial level

| PRODUCT SUMMARY | | | | |
|--------------------|-------|--|--|--|
| I _{F(AV)} | 200 A | | | |

TYPICAL APPLICATIONS

- Converters
- · Power supplies
- · Machine tool controls
- · High power drives
- · Medium traction applications

| MAJOR RATIN | MAJOR RATINGS AND CHARACTERISTICS | | | | |
|---------------------|-----------------------------------|--------------|-------|-------------------|--|
| PARAMETER | TEST CONDITIONS | SD2001 | UNITS | | |
| PARAMETER | TEST CONDITIONS | 1600 to 2000 | 2400 | UNITS | |
| 1 | | 200 | | А | |
| I _{F(AV)} | T _C | 110 | | °C | |
| I _{F(RMS)} | | 314 | | | |
| 1 | 50 Hz | 4700 | | A | |
| I _{FSM} | 60 Hz | 4920 | | | |
| I ² t | 50 Hz | 110 | | 1.42- | |
| 1 - T | 60 Hz | 101 | | kA ² s | |
| V _{RRM} | Range | 1600 to 2000 | 2400 | V | |
| T _J | | - 40 to 180 | 150 | °C | |

ELECTRICAL SPECIFICATIONS

| VOLTAGE RATINGS | | | | | | |
|-----------------|-----------------|--|--|--|--|--|
| TYPE NUMBER | VOLTAGE CODE | V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | $\begin{aligned} & I_{RRM} \text{ MAXIMUM} \\ \text{AT T}_J &= T_J \text{ MAXIMUM} \\ & \text{mA} \end{aligned}$ | | |
| | 16 | 1600 | 1700 | | | |
| SD200N/R | 20 | 2000 | 2100 | 15 | | |
| | 24 | 2400 | 2500 | | | |

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SD200N/R Series



Vishay High Power Products Standard Recovery Diodes (Stud Version), 200 A

| FORWARD CONDUCTION | | | | | | |
|--|--|---|------------------------|-----------------------------|-------|-------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS | |
| Maximum average forward current | | | | 200 | А | |
| at case temperature | I _{F(AV)} 180° conduction, half sine wave | 4000 and attended to the | | 110 | °C | |
| Maximum average forward current | IF(AV) | I _{F(AV)} 180° conduc | action, nan sine | wave | 220 | Α |
| at case temperature | | | | | 100 | °C |
| Maximum RMS forward current | I _{F(RMS)} | DC at 95 ° | C case tempera | ature | 314 | |
| | | t = 10 ms | No voltage | | 4700 | |
| Maximum peak, one-cycle forward, | l=a | t = 8.3 ms | reapplied | | 4920 | А |
| non-repetitive surge current | I _{FSM} | t = 10 ms | 100 % V _{RRM} | | 3950 | |
| | | t = 8.3 ms | reapplied | Sinusoidal half wave, | 4140 | |
| | l ² t | t = 10 ms | No voltage | initial $T_J = T_J$ maximum | 110 | kA ² s |
| Maximum 12t for fusing | | t = 8.3 ms | reapplied | | 101 | |
| Maximum I ² t for fusing | | t = 10 ms | 100 % V _{RRM} | | 78 | |
| | | t = 8.3 ms | reapplied | | 71 | |
| Maximum I ² √t for fusing | I²√t | t = 0.1 to 10 ms, no voltage reapplied | | 1100 | kA²√s | |
| Low level value of threshold voltage | V _{F(TO)1} | (16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), $T_J = T_J$ maximum | | 0.90 | V | |
| High level value of threshold voltage | V _{F(TO)2} | $(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$ | | 1.00 | | |
| Low level value of forward slope resistance | r _{f1} | (16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum | | 0.79 | mΩ | |
| High level value of forward slope resistance | r _{f2} | $(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$ | | 0.64 | 11175 | |
| Maximum forward voltage drop | V _{FM} | $I_{pk} = 630 \text{ A}, T_J = T_J \text{ maximum},$ $t_p = 10 \text{ ms sinusoidal wave}$ | | 1.40 | V | |

| THERMAL AND MECHANICAL SPECIFICATIONS | | | | | |
|--|--------------------------|---|-------------|--------------|------|
| PARAMETER | R SYMBOL TEST CONDITIONS | TECT COMPLETIONS | SD200 | UNITS | |
| PANAMETEN | | 1600 to 2000 | 2400 | UNITS | |
| Maximum junction operating temperature range | T_J | | - 40 to 180 | - 40 to 150 | °C |
| Maximum storage temperature range | T _{Stg} | - 55 to 200 | | 200 | |
| Maximum thermal resistance, junction to case | R _{thJC} | DC operation | 0.23 | | K/W |
| Maximum thermal resistance, case to heatsink | R _{thCS} | Mounting surface, smooth, flat and greased 0.08 | | 8 | K/VV |
| Maximum allowed mounting torque ± 10 % | | Not-lubricated threads 14 | | ļ | Nm |
| Approximate weight | | | 12 | 0 | g |
| Case style | | See dimensions (link at the end of datasheet) | DO-2 | 05AC (DO-30) | |



Standard Recovery Diodes Vishay High Power Products (Stud Version), 200 A

| △R _{thJC} CONDUCTION | | | | | |
|-------------------------------|-----------------------|------------------------|---------------------|-------|--|
| CONDUCTION ANGLE | SINUSOIDAL CONDUCTION | RECTANGULAR CONDUCTION | TEST CONDITIONS | UNITS | |
| 180° | 0.041 | 0.030 | | | |
| 120° | 0.049 | 0.051 | | | |
| 90° | 0.063 | 0.068 | $T_J = T_J$ maximum | K/W | |
| 60° | 0.093 | 0.096 | | | |
| 30° | 0.156 | 0.157 | | | |

Note

• The table above shows the increment of thermal resistance RthJC when devices operate at different conduction angles than DC

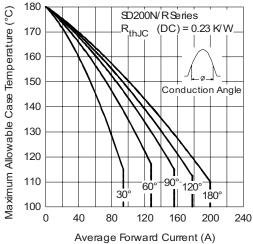


Fig. 1 - Current Ratings Characteristics

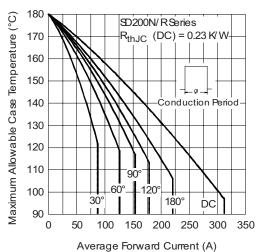


Fig. 2 - Current Ratings Characteristics

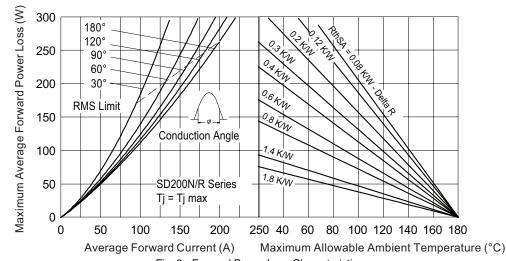


Fig. 3 - Forward Power Loss Characteristics

Vishay High Power Products Standard Recovery Diodes (Stud Version), 200 A



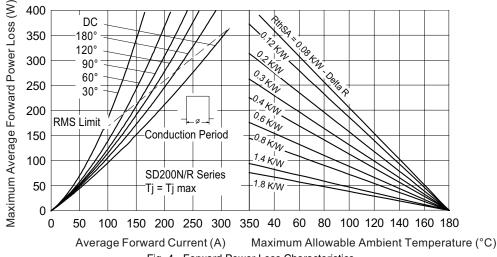
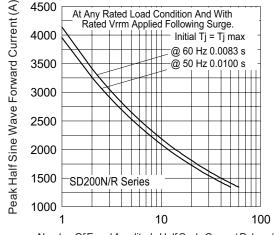
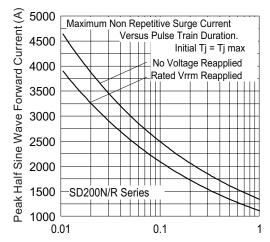


Fig. 4 - Forward Power Loss Characteristics



Number Of Equal Amplitude Half Cycle Current Pulses (N) Fig. 5 - Maximum Non-Repetitive Surge Current



Pulse Train Duration (s) Fig. 6 - Maximum Non-Repetitive Surge Current

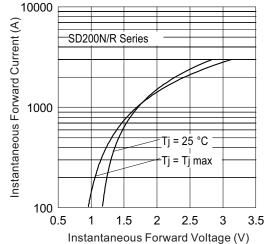


Fig. 7 - Forward Voltage Drop Characteristics



Standard Recovery Diodes Vishay High Power Products (Stud Version), 200 A

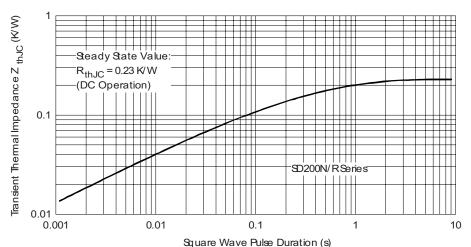
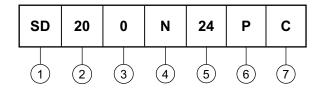


Fig. 8 - Thermal Impedance Z_{thJC} Characteristic

ORDERING INFORMATION TABLE

Device code



- 1 Diode
- 2 Essential part number
- 3 0 = Standard recovery
- 4 • N = Stud normal polarity (cathode to stud)
 - R = Stud reverse polarity (anode to stud)
- 5 Voltage code x 100 = V_{RRM} (see Voltage Ratings table)
- 6 • P = Stud base DO-205AC (DO-30) 1/2" 20UNF-2A
 - M = Stud base DO-205AC (DO-30) M12 x 1.75
- 7 C = Ceramic housing

For metric device M12 x 1.75 contact factory

| LINKS TO RELATED DOCUMENTS | | | |
|--|--|--|--|
| Dimensions http://www.vishay.com/doc?95302 | | | |

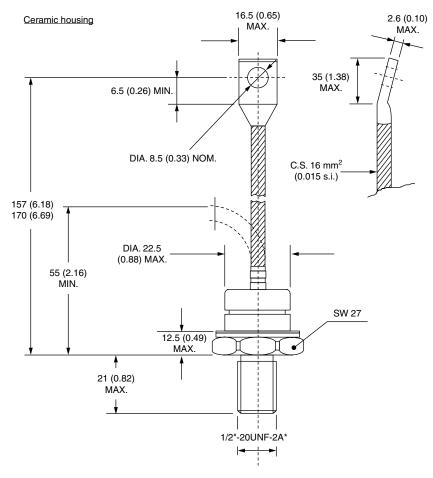
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Vishay Semiconductors

DO-205AC (DO-30)

DIMENSIONS in millimeters (inches)



*For metric device: M12 x 1.75 contact factory



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Vishay

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